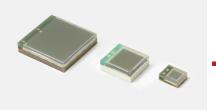


MPPC® (multi-pixel photon counter)



S14160-1310PS/-3010PS/-6010PS etc.

Low breakdown voltage, wide dynamic range type MPPC with small pixels

These are small pixel MPPCs that feature a wide dynamic range. Even with an extremely narrow pixel pitch of 10 or 15 µm, it features high fill factor, reduced crosstalk, and dark count.

Features

- Small pixel pitch (10 μm, 15 μm)
- High fill factor
- → Wide dynamic range
- Low voltage operation (VBR=38 V typ.)
- Low crosstalk and afterpulses
- → High gain: 10⁵ order

Applications

- High energy physics experiments
- **→** Fluorescence measurement
- ➡ Flow cytometry
- DNA sequencers
- **■** Environmental analysis

Structure

Type no.	Photosensitive area (mm)	Pixel pitch (µm)	Number of pixels	Fill factor (%)	Package	Window material	Window refractive index
S14160-1310PS	1.3 × 1.3		16663				
S14160-3010PS	3 × 3	10	89984	31			
S14160-6010PS NEW	6 × 6		359011		Ceramic	Silicone resin	1.57
S14160-1315PS	1.3 × 1.3		7284		Ceramic	Silicone resili	1.57
S14160-3015PS	3 × 3	15	39984	49			
S14160-6015PS NEW	6 × 6		159565				

- Absolute maximum ratings (Ta=25 °C)

Type no.	Reverse voltage Vr (V)	Operating temperature Topr*1 (°C)	Storage temperature Tstg*1 (°C)	Soldering temperature (°C)
S14160-1310PS				
S14160-3010PS				
S14160-6010PS NEW	48	-40 to +60	-40 to +85	240* ²
S14160-1315PS	40	-40 to +60	-40 to +65	(3 times)
S14160-3015PS				
S14160-6015PS NEW				

^{*1:} No dew condensation.

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

^{*2:} Reflow soldering, JEDEC J-STD-020 MSL 2a, see P.9

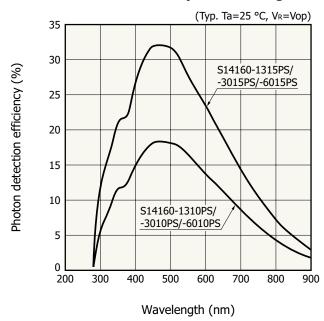
■ Electrical and optical characteristics (Typ. Ta=25 °C, VR=Vop, unless otherwise noted)

Type no.	Spectral response range λ (nm)	Peak sensitivity wavelength λp (nm)	Photon detection wavelength at λp* ³ PDE (%)	Breakdown voltage V _{BR} (V)	Recommended operating voltage*4 Vop (V)	Vop variation within a reel (V)
S14160-1310PS			10		\/ F	
S14160-3010PS S14160-6010PS NEW	-		18		VBR + 5	
S14160-1315PS	290 to 900	460		38 ± 3		±0.1
S14160-3015PS			32		VBR + 4	
S14160-6015PS NEW						

Type no.	Dark cou DO	int rate*5 CR	Direct crosstalk probability	Terminal capacitance at Vop*6	Gain	Temperature coefficient of Vop
туре по.	typ. (kcps)	max. (kcps)	Pct (%)	Ct (pF)	М	ΔTVop (mV/°C)
S14160-1310PS	120	360		100		
S14160-3010PS	700	2100		530	1.8×10^{5}	
S14160-6010PS NEW	3000	10000	<1	2200		34
S14160-1315PS	120	360		100		77
S14160-3015PS	700	2100		530	3.6×10^{5}	
S14160-6015PS NEW	3000	10000		2200		

^{*3:} Photon detection efficiency does not include crosstalk and afterpulse.

Photon detection efficiency vs. wavelength



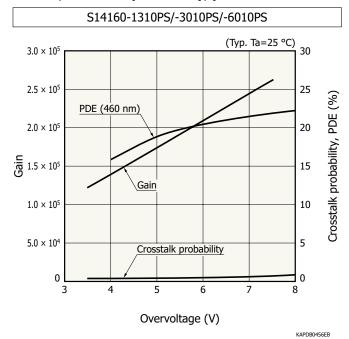
KAPDB0455EB

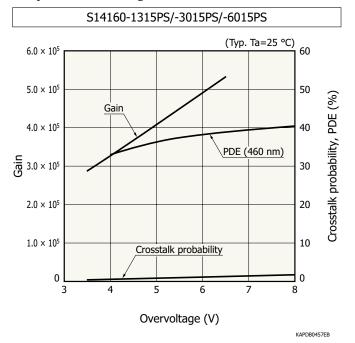
^{*4:} Refer to the data attached for each product.

^{*5:} Threshold=0.5 p.e.

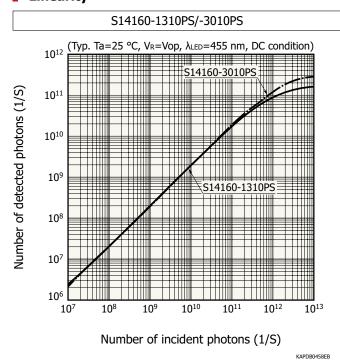
^{*6:} f=100 kHz

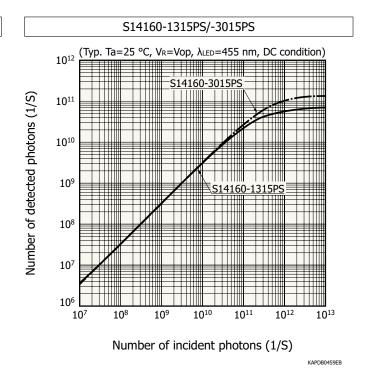
► Gain, crosstalk probability, photon detection efficiency vs. over voltage



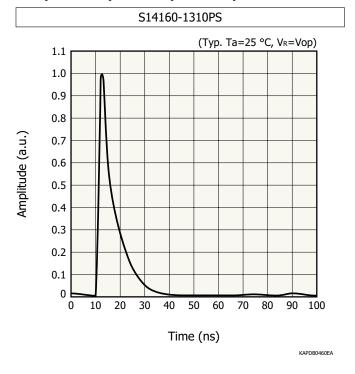


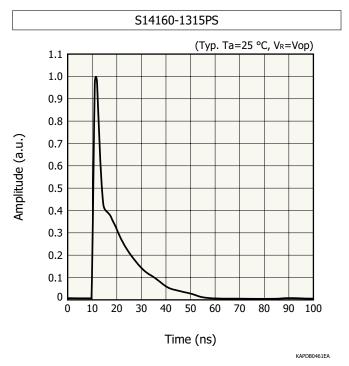
Linearity



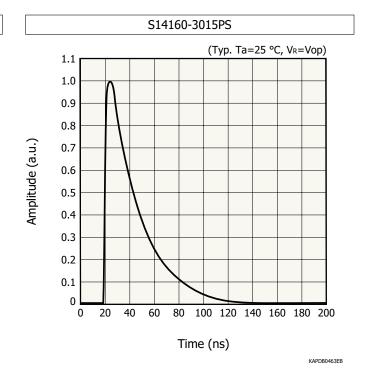


- 1 photon equivalent pulse output



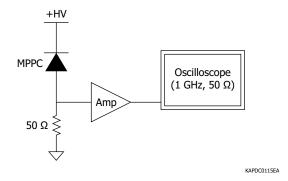


S14160-3010PS (Typ. Ta=25 °C, V_R=Vop) 1.0 0.9 8.0 Amplitude (a.u.) 0.7 0.6 0.5 0.4 0.3 0.2 0.1 80 100 120 140 160 180 200 40 Time (ns) KAPDB0462EB



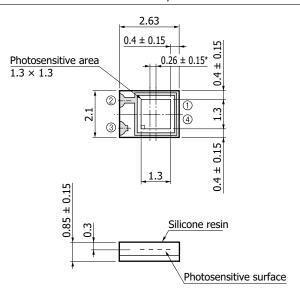
HAMAMATSU PHOTON IS OUR BUSINESS

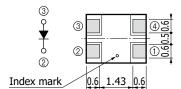
■ Waveform measurement setup



Dimensional outlines (unit: mm)

S14160-1310PS/-1315PS





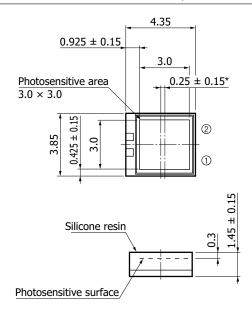
- ① NC
- ② Cathode
- ③ Anode
- \bigcirc NC

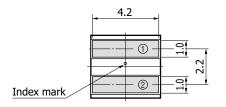
Tolerance unless otherwise noted: ± 0.1

* Distance from chip center to package center

KAPDA0205EB

S14160-3010PS/-3015PS

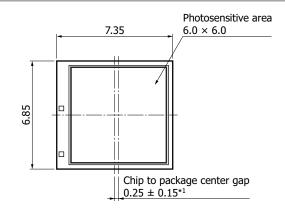


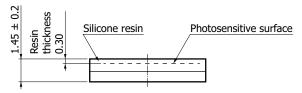


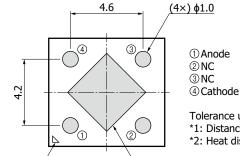
Tolerance unless otherwise noted: ±0.1
* Distance from chip center to package center

KAPDA0206EB

S14160-6010PS/-6015PS







□3.5*²

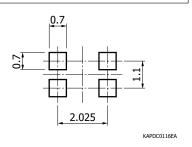
Tolerance unless otherwise noted: ±0.1

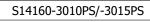
- *1: Distance from chip center to package center
- *2: Heat dissipation pad. Grounding is recommended.

KAPDA0232EA

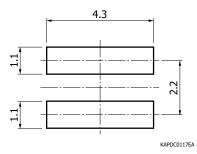
- Recommended land patten (unit: mm)



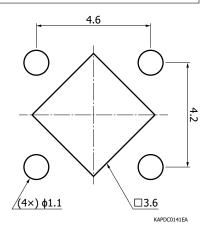




/Index mark



S14160-6010PS/-6015PS



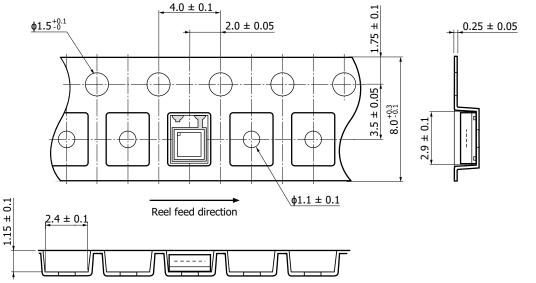
Standard packing specifications

S14160-1310PS/-	1315PS
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■ Reel (conforms to JEITA ET-7200)

Reel diameter	Hub diameter	Tape width	Material	Electrostatic characteristics
180 mm	60 mm	8 mm	PS (polystyrene)	Conductive

■ Embossed tape (unit: mm, material: PS, conductive)



KAPDC0101EA

- Packing quantity 300 pcs/reel
- Packing type

 Reel and desiccant in moisture-proof packaging (vacuum-sealed)
- Label

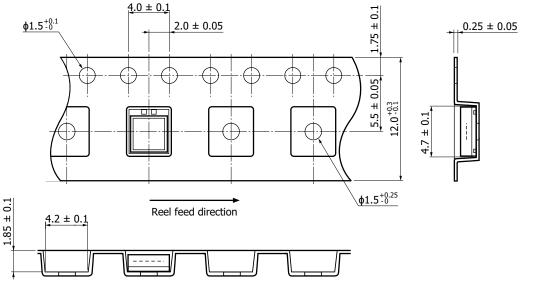
Type No
Lot No.
Vop
HAMAMATSU
MADE IN JAPAN

S14160-3010PS/-3015PS

■ Reel (conforms to JEITA ET-7200)

Reel diameter	Hub diameter	Tape width	Material	Electrostatic characteristics
254 mm	80 mm	12 mm	PS (polystyrene)	Conductive

■ Embossed tape (unit: mm, material: PS, conductive)



KAPDC0118EA

- Packing quantity 300 pcs/reel
- Packing type

 Reel and desiccant in moisture-proof packaging (vacuum-sealed)
- Label

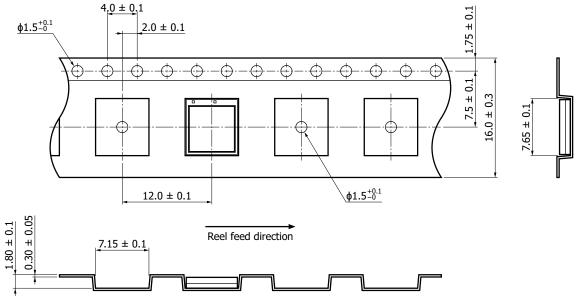
Type No
Lot No.
Vop
HAMAMATSU
MADE IN JAPAN

S14160-6010PS/-6015PS

■ Reel (conforms to JEITA ET-7200)

Reel diameter	Hub diameter	Tape width	Material	Electrostatic characteristics
254 mm	80 mm	16 mm	PS (polystyrene)	Conductive

■ Embossed tape (unit: mm, material: PPE, conductive)



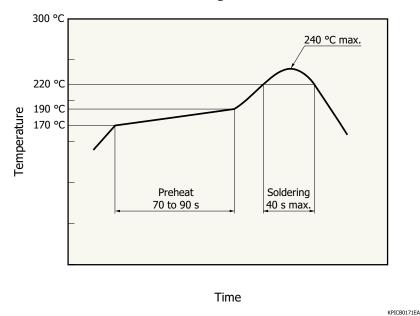
KAPDC0142EA

- Packing quantity 300 pcs/reel
- Packing type

 Reel and desiccant in moisture-proof packaging (vacuum-sealed)
- Label

Type No	
Lot No	
Vop	
HAMAMATSI	J
	MADE IN JAPAN

Recommended reflow soldering conditions



- This surface mount type product supports lead-free soldering. After unpacking, store it in an environment at a temperature of 30 °C or less and a humidity of 60% or less, and perform soldering within 4 weeks.
- This effect that the product receives during reflow soldering varies depending on the circuit board and reflow oven that are used. When you set reflow soldering conditions, cheek that problems do not occur in the product by testing out the conditions in advance.

Baking

If 4 weeks have passed in an unpacked state, or the storage period in the table above has passed after opening, perform baking before reflow soldering to behumidify. For the baking, refer to the precautions "Surface mount type products."

■ Recommended baking conditions

Temperature: 150 °C, 3 hours, up to twice

Note: When you set baking conditions, check that problems do not occur in the product by testing out the conditions in advance.

Precautions

· If necessary, incorporate appropriate protective circuits in power supplies, devices, and measuring instruments to prevent overvoltage and overcurrent.

- Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- · Disclaimer
- Surface mount type products
- Technical note
- · MPPC



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The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

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